

RoHS

COMPLIANT HALOGEN

FREE Available

Vishay Siliconix

N-Channel 200-V (D-S) MOSFET

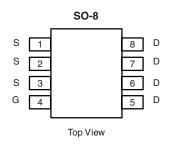
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
200	0.240 at V _{GS} = 10 V	2.2		
	0.260 at V _{GS} = 6.0 V	2.1		

FEATURES

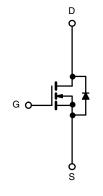
- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFET
- PWM Optimized for Low Q_{g} and Low R_{g}
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

• Primary Side Switch



Ordering Information: Si4464DY-T1-E3 (Lead (Pb)-free) Si4464DY-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \text{ °C}$, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	200		V	
Gate-Source Voltage		V _{GS}	± 20			
	T _A = 25 °C	1-	2.2	1.7		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	– I _D	1.7	1.3	٨	
Pulsed Drain Current		I _{DM}	8		A	
Single Avalanch Current	L = 0.1 mH	I _{AS}	3 0.45			
Single Avalanch Energy		E _{AS}			mJ	
Continuous Source Current (Diode Conduction) ^a		۱ _S	2.1	1.2	А	
	T _A = 25 °C	Р	2.5 1.5		W	
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	1.6	0.9	vv	
Operating Junction and Storage Temperature Rar	T _J , T _{stg}	- 55 to 150		°C		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lunation to Ambienta	t ≤ 10 s	R _{thJA}	37	50	
Maximum Junction-to-Ambient ^a	Steady State		68	85	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	17	21	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted								
Parameter	Symbol	Test Conditions		Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2.0		4	V		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V$, $V_{GS} = \pm 20 V$			± 100	nA		
	1	V _{DS} = 200 V, V _{GS} = 0 V			1			
Zero Gate Voltage Drain Current	IDSS	V_{DS} = 200 V, V_{GS} = 0 V, T_{J} = 55 °C			5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, V_{GS} = 10 V	8			А		
	D	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 2.2 \text{ A}$		0.195	0.240	0		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 6.0 \text{ V}, \text{ I}_{\text{D}} = 2.1 \text{ A}$		0.210	0.260	Ω		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 2.2 \text{ A}$		8.0		S		
Diode Forward Voltage ^a	V _{SD}	I _S = 2.1 A, V _{GS} = 0 V		0.8	1.2	V		
Dynamic ^b								
Total Gate Charge	Qg			12	18			
Gate-Source Charge	Q _{gs}	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 2.2 \text{ A}$		2.5		nC		
Gate-Drain Charge	Q _{gd}			3.8				
Gate Resistance	R _g			2.5		Ω		
Turn-On Delay Time	t _{d(on)}			10	15			
Rise Time	t _r	V_{DD} = 100 V, R_L = 100 Ω		12	20			
Turn-Off Delay Time	t _{d(off)}	${\rm I}_{\rm D}\cong$ 1 A, ${\rm V}_{\rm GEN}$ = 10 V, ${\rm R}_{\rm g}$ = 6 Ω		15	25	ns		
Fall Time	t _f			15	25			
Source-Drain Reverse Recovery Time t _{rr}		I _F = 2.1 A, dI/dt = 100 A/μs		60	90			

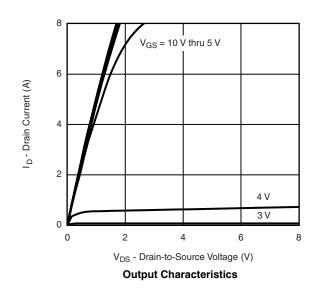
Notes:

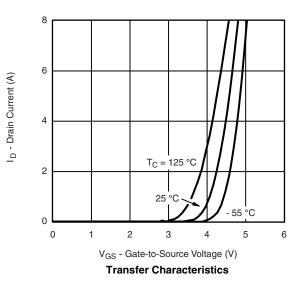
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

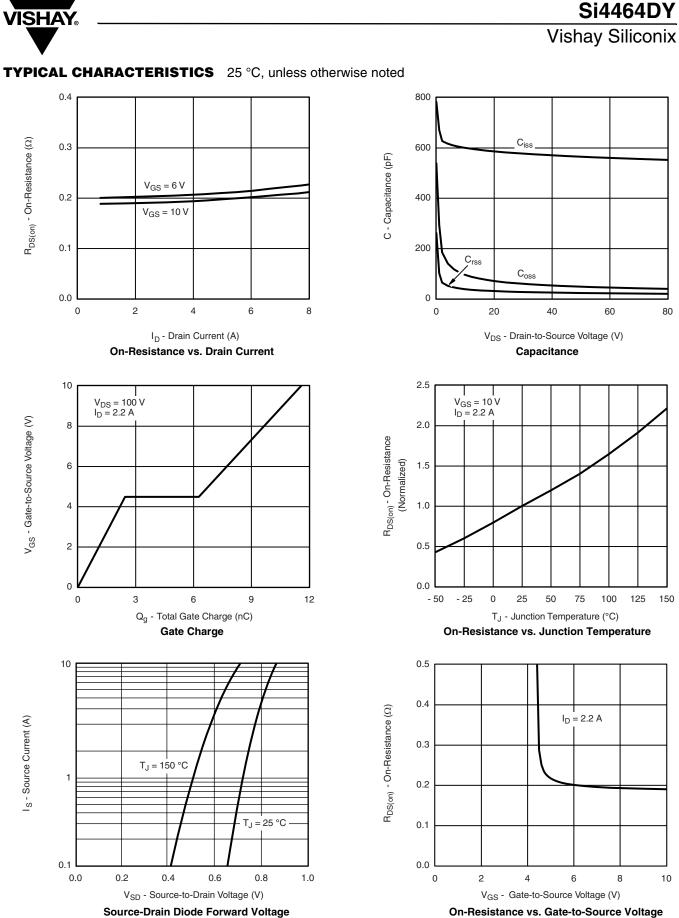
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted







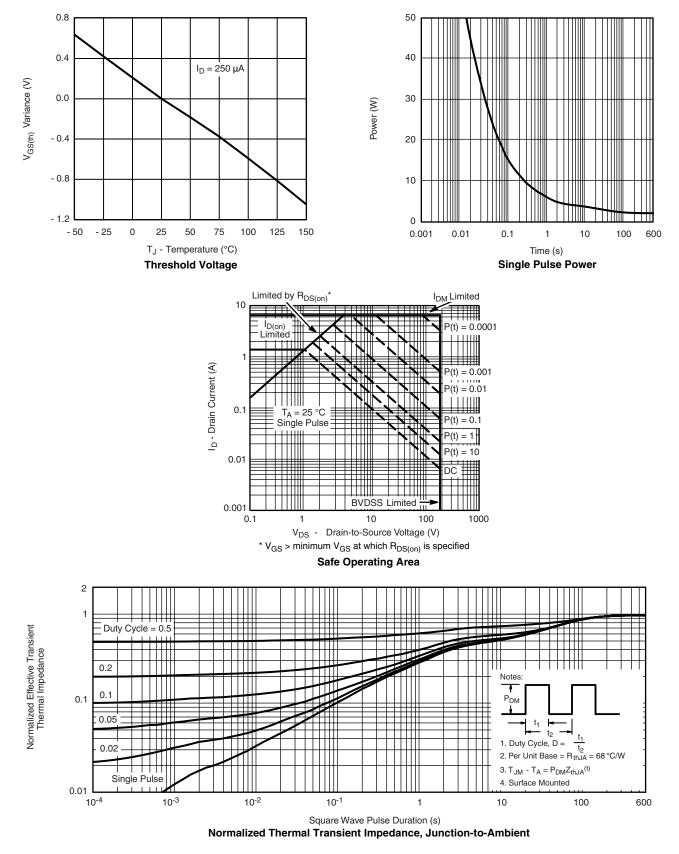
Source-Drain Diode Forward Voltage

Document Number: 72051 S09-0705-Rev. C, 27-Apr-09

Si4464DY

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

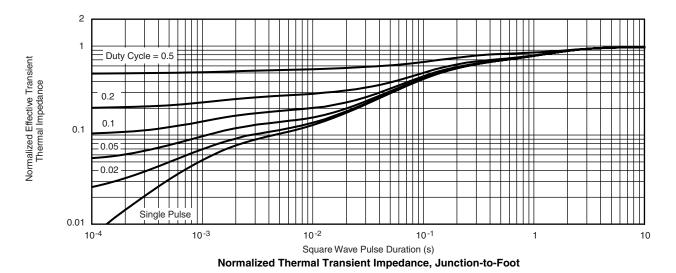






Si4464DY Vishay Siliconix

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?72051.



Package Information

Vishay Siliconix

SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012





	MILLIM	IETERS	INCHES			
DIM	Min	Мах	Min	Max		
A	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
E	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498						

Application Note 826

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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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